LXA20T600 Qspeed[™] Family

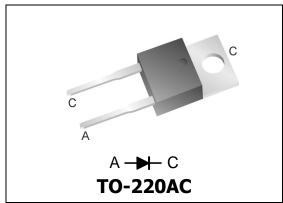
Power integrations**

600 V, 20 A X-Series PFC Diode

Product Summary

I _{F(AVG)}	20	Α
V_{RRM}	600	٧
Q _{RR} (Typ at 125 °C)	140	nC
I _{RRM} (Typ at 125 °C)	5.0	Α
Softness t _v /t _a (Typ at 125 °C)	0.4	

Pin Assignment



RoHS Compliant

Package uses Lead-free plating and Green mold compound. Halogen free per IEC 61249-2-21.

General Description

This device has the lowest Q_{RR} of any 600 V Silicon diode. Its recovery characteristics increase efficiency, reduce EMI and eliminate snubbers.

Applications

- Power Factor Correction (PFC) boost diode
- · Motor drive circuits
- DC-AC inverters

Features

- Low Q_{RR}, low I_{RRM}, low t_{RR}
- High dI_F/dt capable (1000 A/µs)
- Soft recovery

Benefits

- · Increases efficiency
 - Eliminates need for snubber circuits
 - Reduces EMI filter component size & count
- Enables extremely fast switching

Absolute Maximum Ratings

Absolute maximum ratings are the values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Symbol	Parameter	Conditions	Rating	Units
V_{RRM}	Peak repetitive reverse voltage		600	V
I _{F(AVG)}	Average forward current	$T_{\rm J} = 150$ °C, $T_{\rm C} = 100$ °C	20	Α
I_{FSM}	Non-repetitive peak surge current	60 Hz, 1/2 cycle	105	Α
I_{FSM}	Non-repetitive peak surge current	$1/2$ cycle of t = 28 μ s Sinusoid, T_C = 25 °C	350	Α
$T_{J(MAX)}$	Maximum junction temperature		150	°C
T_{STG}	Storage temperature		-55 to 150	°C
	Lead soldering temperature	Leads at 1.6 mm from case, 10 sec	300	°C
P_{D}	Power dissipation	T _C = 25 °C	125	W
V_{RRM}	Peak repetitive reverse voltage		600	V

Thermal Resistance

Symbol	Resistance from:	Conditions	Rating	Units
$R_{\theta JA}$	Junction to ambient	TO-220	62	°C/W
$R_{\theta JC}$	Junction to case	TO-220	1.0	°C/W

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Electrical Specifications at $T_J = 25$ °C (unless otherwise specified)

Symbol	Parameter	Conditions		Min	Тур	Max	Units
DC Chara	DC Characteristics						
т	Dovers surrent	V _R = 600 V, T _J = 25 °C		-	-	250	μΑ
I_{R}	Reverse current	$V_R = 600 \text{ V}, T_J = 125 ^{\circ}$	С	-	2.0	-	mA
V	Forward voltage	$I_F = 20 \text{ A, } T_J = 25 ^{\circ}\text{C}$		-	2.5	3.1	V
V_{F}	Forward voltage	I _F = 20 A, T _J = 150 °C		-	2.3	-	V
C_{J}	Junction capacitance	$V_R = 10 \text{ V}, 1 \text{ MHz}$		-	92	-	pF
Dynamic	Characteristics						
+	Payarsa rasayary tima	dI/dt = 200 A/μs	T _J = 25 °C	-	26.5	-	ns
t_RR	Reverse recovery time	$V_R = 400 \text{ V}, I_F = 20 \text{ A}$	T _J = 125 °C	-	41.3	-	ns
0	Doverse recovery charge	dI/dt = 200 A/μs	T _J = 25 °C	-	51	80	nC
Q_{RR}	Reverse recovery charge	$V_R = 400 \text{ V}, I_F = 20 \text{ A}$	T _J = 125 °C	-	140	-	nC
т	Maximum reverse	dI/dt = 200 A/μs	T _J = 25 °C	-	3.0	4.0	Α
I_{RRM}	recovery current	$V_R = 400 \text{ V}, I_F = 20 \text{ A}$	T _J = 125 °C	-	5.0	-	Α
_	Softness factor = $\frac{t_b}{t_b}$	dI/dt = 200 A/μs	T _J = 25 °C	-	0.7	-	
S	Somess factor = $\frac{z}{t_a}$	$V_R = 400 \text{ V}, I_F = 20 \text{ A}$	T _J = 125 °C	-	0.4	-	

Note to component engineers: X-Series diodes employ Schottky technologies in their design and construction. Therefore, Component Engineers should plan their test setups to be similar to those for traditional Schottky test setups. (For additional details, see Application Note AN-300.)

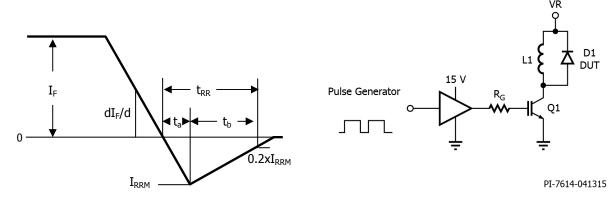
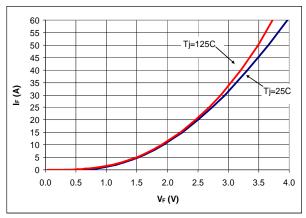


Figure 1. Reverse Recovery Definitions

Figure 2. Reverse Recovery Test Circuit

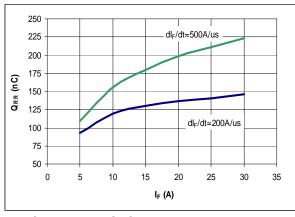
Electrical Specifications at $T_1 = 25$ °C (unless otherwise specified)



400 350 300 250 200 150 100 0 20 40 60 80 100 120 140 160 180 V_R (V)

Figure 3. Typical I_F vs V_F

Figure 4. Typical C_i vs V_R



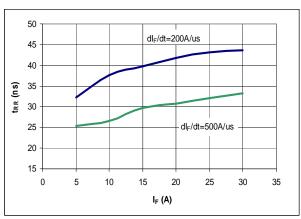
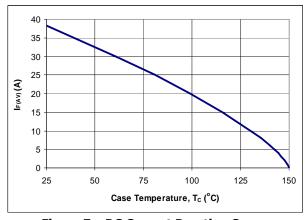


Figure 5. Typical Q_{RR} vs I_F at T_J = 125 °C

Figure 6. Typical t_{RR} vs I_F at $T_J = 125$ °C



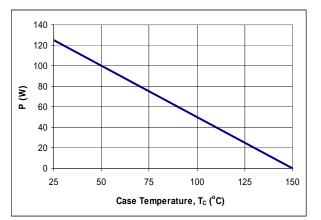


Figure 7. DC Current Derating Curve

Figure 8. Power Derating Curve

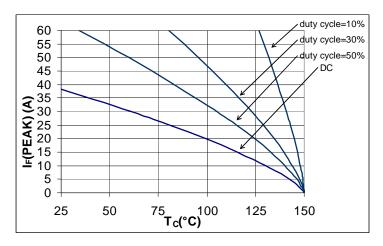


Figure 9. $I_F(PEAK)$ vs T_C , f=70 kHz

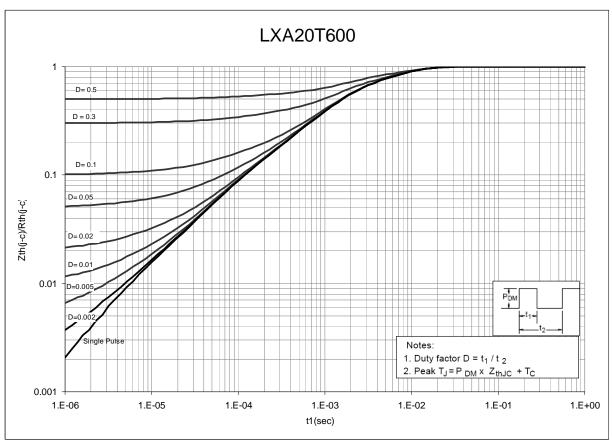
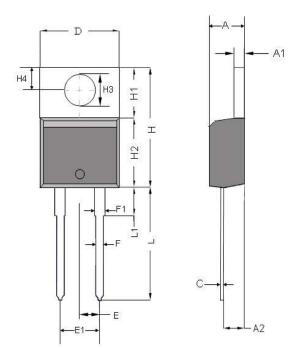


Figure 10. Normalized Maximum Transient Thermal Impedance

Dimensional Outline Drawings



	Millimeters		
Dim	MIN	MAX	
A	4.32	4.70	
A1	1.14	1.40	
A2	2.03	2.79	
С	0.34	0.610	
D	9.65	10.67	
E	2.49	2.59	
E1	4.98	5.18	
F	0.508	1.016	
F1	1.14	1.78	
Н	14.71	16.51	
H1	5.84	6.55	
H2	8.51	9.25	
Н3	3.53	3.96	
H4	2.54	3.05	
L	12.70	14.22	
L1	-	6.35	

Mechanical Mounting Method	Maximum Torque / Pressure specification	
Screw through hole in package tab	1 Newton Meter (nm) or 8.8 inch-pounds (lb-in)	
Clamp against package body	12.3 kilogram-force per square centimeter (kgf/cm²) or 175 lbf/in²	

Soldering time and temperature: This product has been designed for use with high-temperature, lead-free solder. The component leads can be subjected to a maximum temperature of 300 °C, for up to 10 seconds. See Application Note AN-303, for more details.

Ordering Information

Part Number	Package	Packing
LXA20T600	TO-220AC	50 units/tube

The information contained in this document is subject to change without notice.

LXA20T600

Revision	Notes	Date
1.0	Released by Qspeed	09/09
1.1	Converted to Power Integrations Document	01/11
1.1	Stop Point of t _{RR} error corrected due to typo in Figure 1	11/13
1.2	Updated with new Brand Style.	06/15



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Power Integrations Worldwide Sales Support Locations

WORLD HEADQUARTERS

5245 Hellyer Avenue San Jose, CA 95138, USA. Main: +1-408-414-9200 Customer Service: Phone: +1-408-414-9665 Fax: +1-408-414-9765

e-mail: usasales@power.com

CHINA (SHANGHAI)

Rm 2410, Charity Plaza, No. 88, North Caoxi Road, Shanghai, PRC 200030 Phone: +86-21-6354-6323 Fax: +86-21-6354-6325 e-mail:_chinasales@power.com

CHINA (SHENZHEN)

17/F, Hivac Building, No. 2, Keji Nan 8th Road, Nanshan District, Shenzhen, China, 518057 Phone: +86-755-8672-8689 Fax: +86-755-8672-8690 e-mail: chinasales@power.com

GERMANY

Lindwurmstrasse 114 80337, Munich Germany Phone: +49-895-527-39110

Fax: +49-895-527-39200

e-mail:

eurosales@power.com

INDIA

#1, 14th Main Road Vasanthanagar Bangalore-560052 India

Phone: +91-80-4113-8020 Fax: +91-80-4113-8023

e-mail:

indiasales@power.com

ITALY

Via Milanese 20, 3rd. Fl. 20099 Sesto San Giovanni (MI) Italy

Phone: +39-024-550-8701 Fax: +39-028-928-6009

e-mail:

eurosales@power.com

JAPAN

Kosei Dai-3 Building 2-12-11, Shin-Yokohama, Kohoku-ku, Yokohama-shi, Kanagawa 222-0033 Japan

Phone: +81-45-471-1021 Fax: +81-45-471-3717

e-mail: japansales@power.com

KOREA

RM 602, 6FL Korea City Air Terminal B/D, 159-6

Samsung-Dong, Kangnam-Gu, Seoul, 135-728 Korea Phone: +82-2-2016-6610

Fax: +82-2-2016-6630 e-mail: koreasales@power.com

SINGAPORE

51 Newton Road, #19-01/05 Goldhill Plaza Singapore, 308900 Phone: +65-6358-2160 Fax: +65-6358-2015

e-mail:

singaporesales@power.com

TAIWAN

5F, No. 318, Nei Hu Rd., Sec. 1 Nei Hu District Taipei 11493, Taiwan R.O.C. Phone: +886-2-2659-4570 Fax: +886-2-2659-4550 e-mail: taiwansales@power.com

UK

First Floor, Unit 15, Meadway Court, Rutherford Close, Stevenage, Herts. SG1 2EF United Kingdom Phone: +44 (0) 1252-730-141 Fax: +44 (0) 1252-727-689 e-mail: eurosales@power.com



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